

ECN/PCN No.: 4127

For Manufacturer			
Product Description: PLASTIC SMD MEMS OSCILLATOR	Abracon Part Number / Part Series: EMK32	<input type="checkbox"/> Documentation only <input type="checkbox"/> ECN <input checked="" type="checkbox"/> EOL	<input checked="" type="checkbox"/> Series <input type="checkbox"/> Part Number
Affected Revision: M	New Revision: EOL	Application:	<input type="checkbox"/> Safety <input checked="" type="checkbox"/> Non-Safety
Prior to Change: Active https://abracon.com/datasheets/Ecliptek/EMK32.pdf			
After Change: EOL			
Cause/Reason for Change: Discontinuation of manufacturing capability.			
Change Plan			
Effective Date: 2/7/2022	Additional Remarks: N/A		
Change Declaration: N/A			
Issued Date: 2/7/2022	Issued By: <i>Brooke Cushman</i> Product Engineer	Issued Department: Engineering	
Approval: <i>Thomas Culhane</i> Engineering Director	Approval: <i>Reuben Quintanilla</i> Quality Director	Approval: <i>Ying Huang</i> Purchasing Director	
For Abracon EOL only			
Last Time Buy (if applicable): 5/7/2022	Alternate Part Number / Part Series: ASEDV (3.2x2.5mm)		
Additional Approval:	Additional Approval:	Additional Approval:	
Customer Approval (If Applicable)			
Qualification Status: <input type="checkbox"/> Approved <input type="checkbox"/> Not accepted <i>Note: It is considered approved if there is no feedback from the customer 1 month after ECN/PCN is released.</i>			
Customer Part Number:		Customer Project:	
Company Name:	Company Representative:	Representative Signature:	
Customer Remarks:			

REGULATORY COMPLIANCE

 <p>Lead Free COMPLIANT</p>	 <p>EU RoHS 2011/65 + 2015/863 COMPLIANT</p>	 <p>China RoHS COMPLIANT</p>	 <p>REACH SVHC COMPLIANT</p>	 <p>DRC CONFLICT FREE</p>
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ITEM DESCRIPTION

MEMS Clock Oscillators LVCMOS (CMOS) 2.5Vdc 4 Pad 2.5mm x 3.2mm Plastic Surface Mount (SMD)

ELECTRICAL SPECIFICATIONS

Nominal Frequency	1MHz to 125MHz
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, and Output Load Change ±100ppm Maximum over 0°C to +70°C ±50ppm Maximum over 0°C to +70°C ±25ppm Maximum over 0°C to +70°C ±20ppm Maximum over 0°C to +70°C ±100ppm Maximum over -20°C to +70°C ±50ppm Maximum over -20°C to +70°C ±25ppm Maximum over -20°C to +70°C ±20ppm Maximum over -20°C to +70°C ±100ppm Maximum over -40°C to +85°C ±50ppm Maximum over -40°C to +85°C ±25ppm Maximum over -40°C to +85°C ±20ppm Maximum over -40°C to +85°C
Aging at 25°C	±1.5ppm Maximum First Year
Supply Voltage	2.5Vdc ±10%
Input Current	No Load 5mA Maximum over Nominal Frequency of 1MHz to 20MHz 6mA Maximum over Nominal Frequency of 20.000001MHz to 50MHz 7mA Maximum over Nominal Frequency of 50.000001MHz to 80MHz 8mA Maximum over Nominal Frequency of 80.000001MHz to 125MHz
Output Voltage Logic High (V_{OH})	I _{OH} = -3mA 90% of V _{DD} Minimum
Output Voltage Logic Low (V_{OL})	I _{OL} = +3mA 10% of V _{DD} Maximum
Rise/Fall Time	Measured from 20% to 80% of waveform 1.2nSec Typical, 3nSec Maximum
Duty Cycle	Measured at 50% of waveform 50 ±10(%) 50 ±5(%)
Load Drive Capability	15pF Maximum
Output Logic Type	CMOS
Output Control Function	Tri-State (Disabled Output: High Impedance) Power Down (Disabled Output: Logic Low)
Output Control Input Voltage Logic High (V_{IH})	70% of V _{DD} Minimum or No Connect to Enable Output
Output Control Input Voltage Logic Low (V_{IL})	30% of V _{DD} Maximum to Disable Output
Power Down Output Enable Time	5mSec Maximum
Tri-State Output Enable Time	150nSec Maximum
Power Down Output Disable Time	150nSec Maximum
Tri-State Output Disable Time	150nSec Maximum
Standby Current	10µA Maximum (Disabled Output: Logic Low)
Period Jitter (RMS)	2pSec Typical, 4pSec Maximum

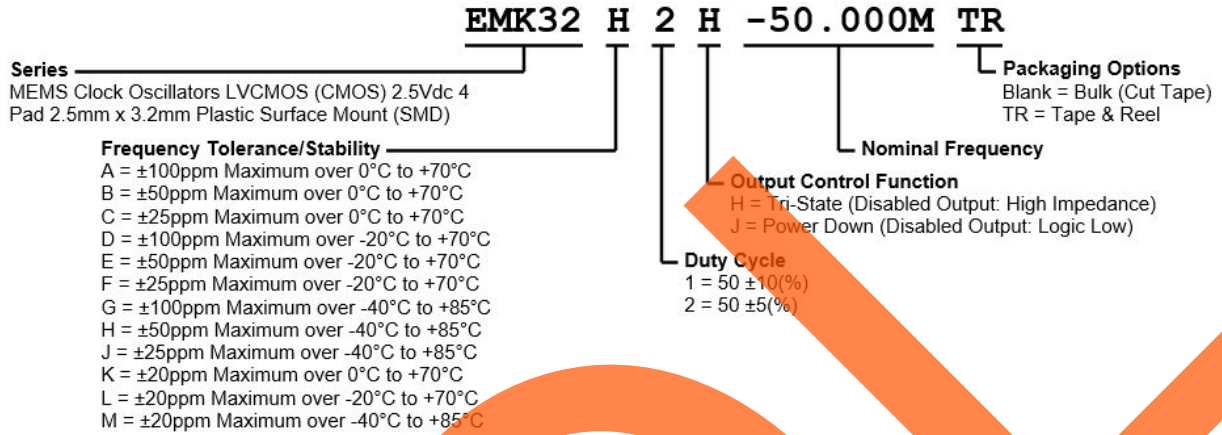
EMK32 Series



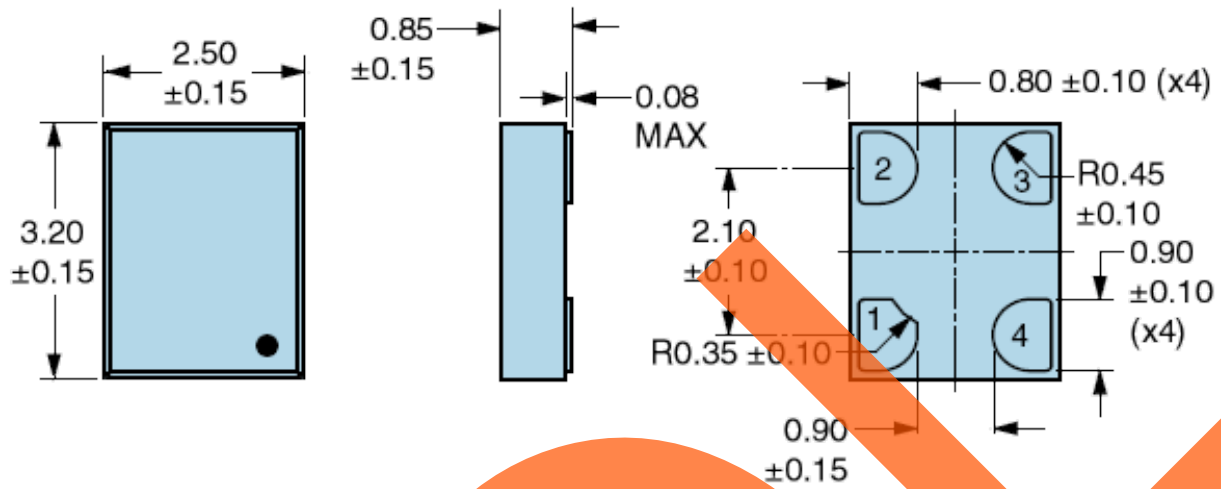
RMS Phase Jitter (Fj = 900kHz to 7.5MHz; Random)	0.5pSec Typical, 1pSec Maximum
RMS Phase Jitter (Fj = 12kHz to 20MHz; Random)	1.5pSec Typical, 3pSec Maximum
Start Up Time	5mSec Maximum
Storage Temperature Range	-65°C to +150°C



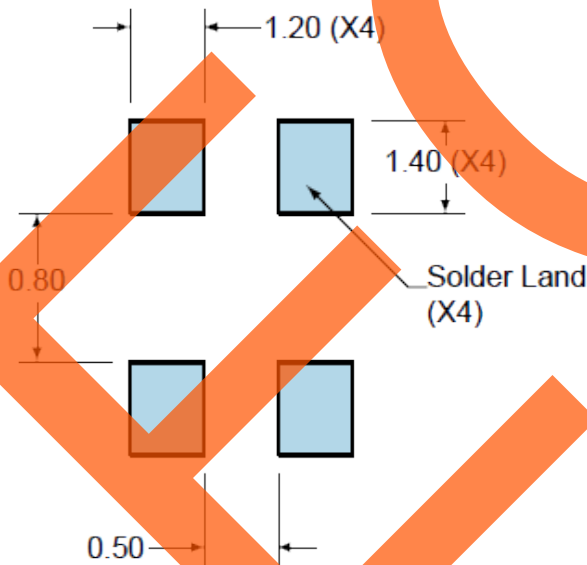
PART NUMBERING GUIDE



MECHANICAL DIMENSIONS



SUGGESTED SOLDER PAD LAYOUT

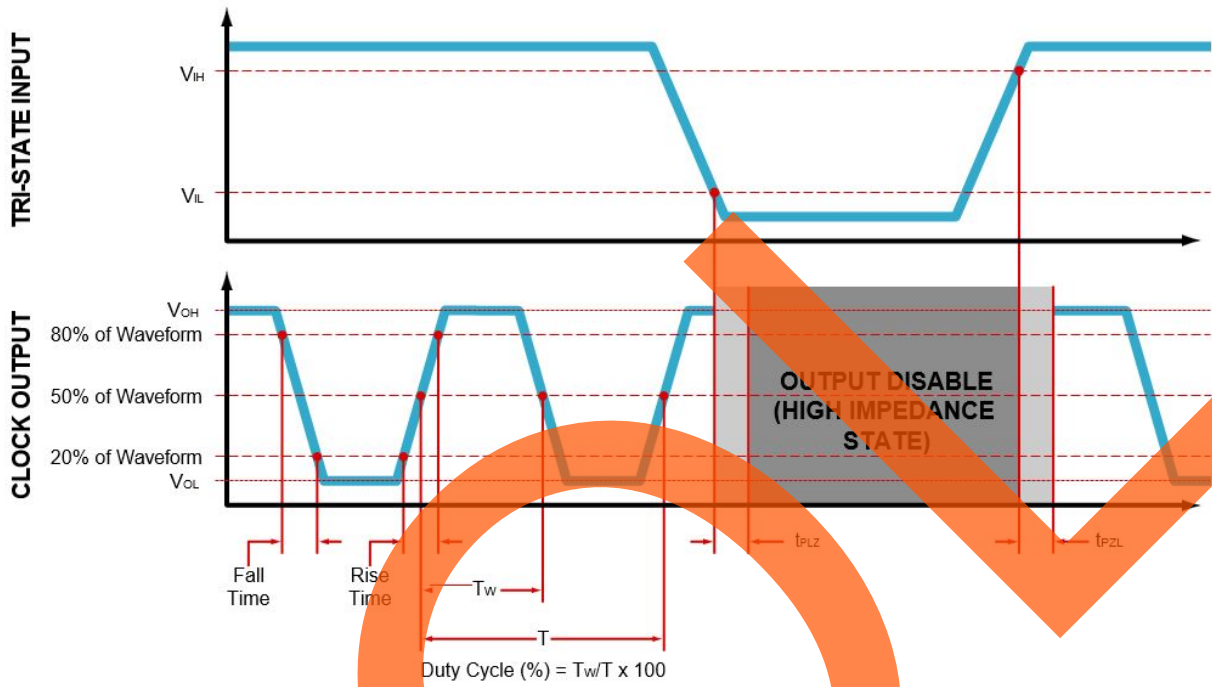


PIN	CONNECTION
1	Power Down Or Tri-State
2	Ground
3	Output
4	Supply Voltage

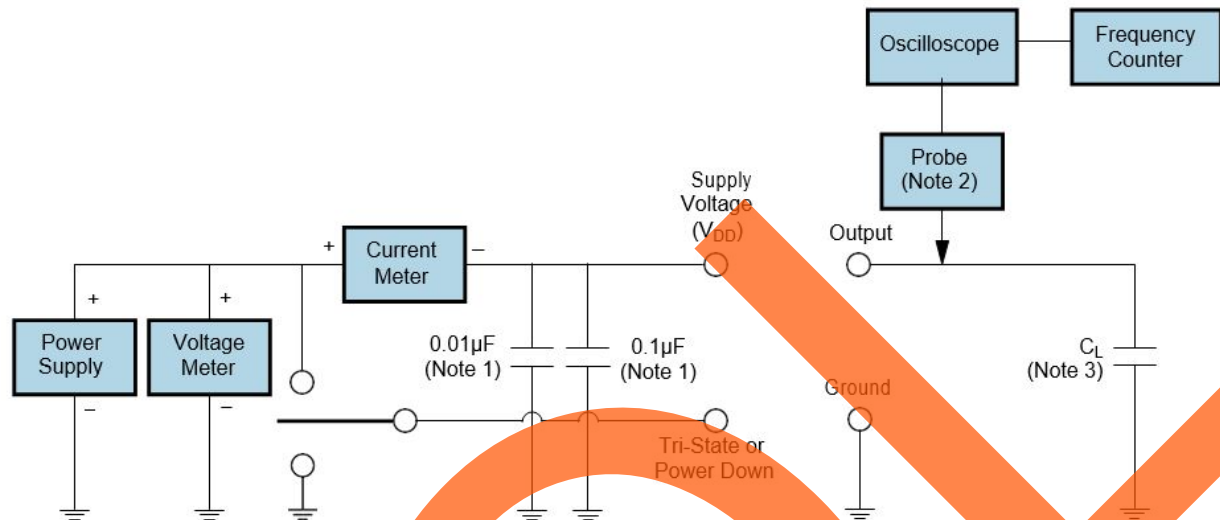
All Tolerances are ±0.1

All Dimensions in Millimeters

OUTPUT WAVEFORM & TIMING DIAGRAM



TEST CIRCUIT FOR CMOS OUTPUT



Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low input capacitance (<12pF), 10X Attenuation Factor, High Impedance (>10Mohms), and High bandwidth (>300MHz) Passive probe is recommended.

Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance. See applicable specification sheet for 'Load Drive Capability'.

TAPE & REEL DIMENSIONS

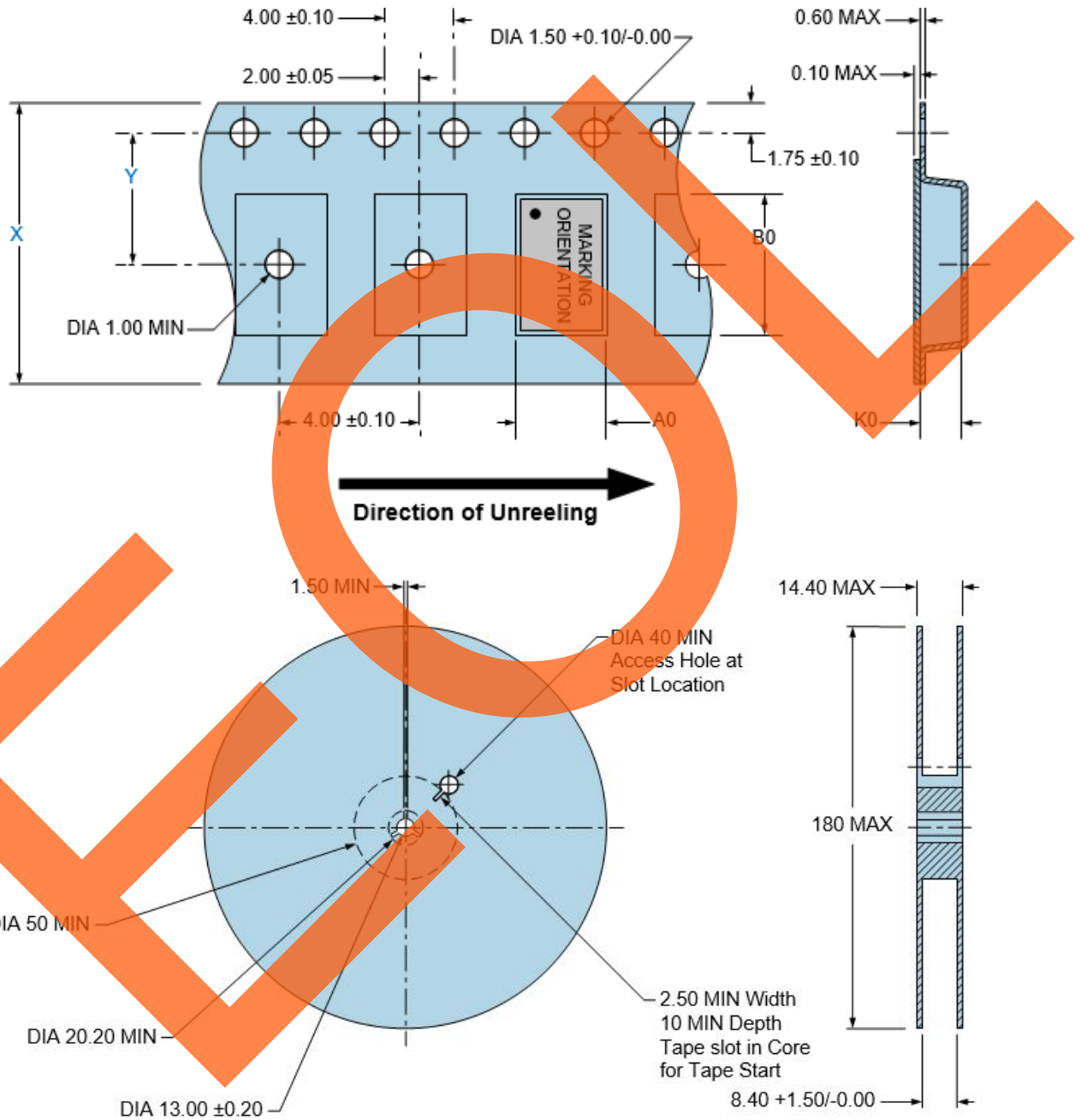
Quantity per Reel: 1,000 Units

All Dimensions in Millimeters

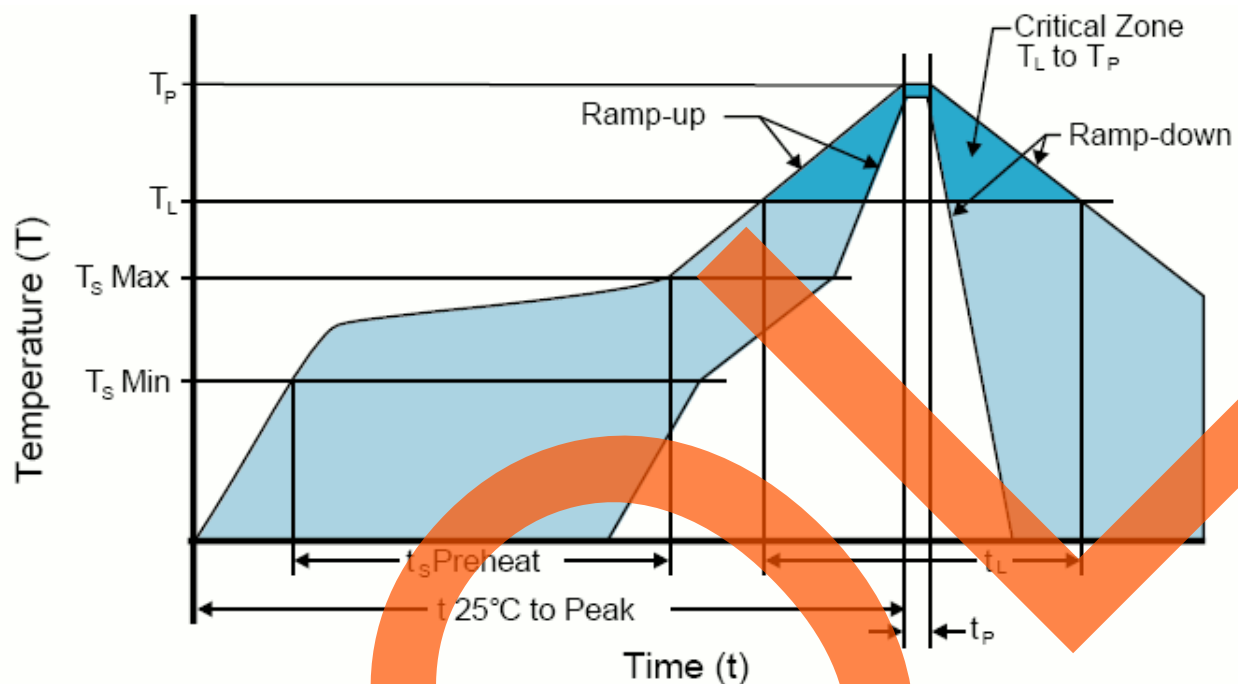
Compliant to EIA-481

X = 8.00±0.30 or 12±0.30

Y = 3.50±0.05 or 5.5±0.05



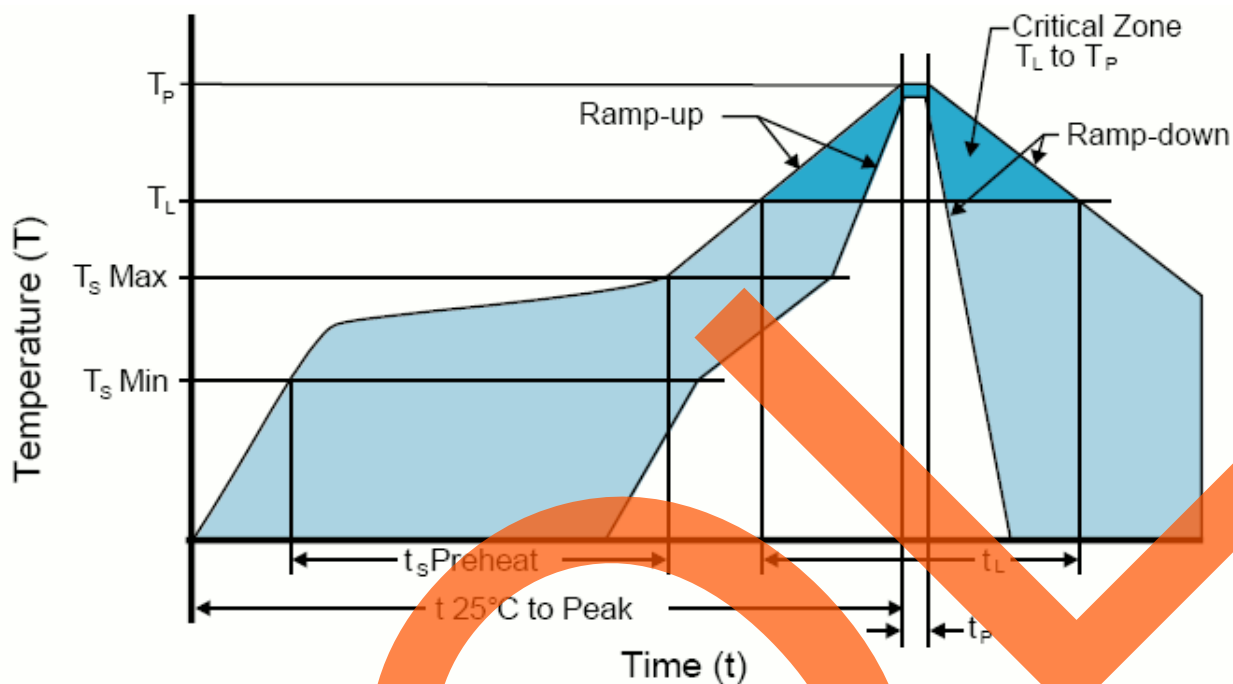
RECOMMENDED SOLDER REFLOW METHOD



HIGH TEMPERATURE INFRARED/CONVECTION

T _S MAX to T _L (Ramp-up Rate)	3°C/Second Maximum
Preheat	
- Temperature Minimum (T _S MIN)	150°C
- Temperature Typical (T _S TYP)	175°C
- Temperature Maximum (T _S MAX)	200°C
- Time (t _S MIN)	60 - 180 Seconds
Ramp-up Rate (T_L to T_P)	3°C/Second Maximum
Time Maintained Above:	
- Temperature (T _L)	217°C
- Time (t _L)	60 - 150 Seconds
Peak Temperature (T_P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T_P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t_p)	20 - 40 Seconds
Ramp-down Rate	6°C/Second Maximum
Time 25°C to Peak Temperature (t)	8 Minutes Maximum
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.

RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION

T _S MAX to T _L (Ramp-up Rate)	5°C/Second Maximum
Preheat	
- Temperature Minimum (T _S MIN)	N/A
- Temperature Typical (T _S TYP)	150°C
- Temperature Maximum (T _S MAX)	N/A
- Time (t _S MIN)	60 - 120 Seconds
Ramp-up Rate (T_L to T_P)	5°C/Second Maximum
Time Maintained Above:	
- Temperature (T _L)	150°C
- Time (t _L)	200 Seconds Maximum
Peak Temperature (T_P)	240°C Maximum
Target Peak Temperature (T_P Target)	240°C Maximum 2 Times / 230°C Maximum 1 Time
Time within 5°C of actual peak (t_p)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time
Ramp-down Rate	5°C/Second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)